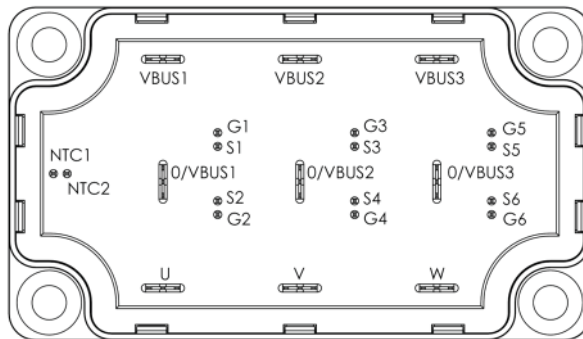
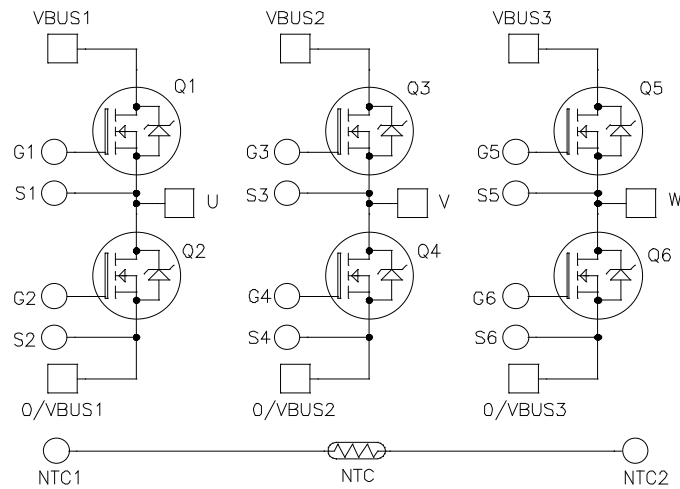


## Triple Phase Leg SiC MOSFET Power Module

### Product Overview

The MSCSM120TAM16TPAG device is a triple phase leg 1200V, 171A silicon carbide (SiC) power module.



**Note:** All ratings at  $T_J = 25\text{ }^\circ\text{C}$ , unless otherwise specified.



These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

## Features

The following are the key features of the MSCSM120TAM16TPAG device:

- SiC Power MOSFET
  - High temperature performance
  - Low  $R_{DS(on)}$
- Very low stray inductance
- Kelvin source for easy drive
- Internal thermistor for temperature monitoring
- Aluminum Nitride (AlN) substrate for improved thermal performance

## Benefits

The following are the benefits of the MSCSM120TAM16TPAG device:

- High power and efficiency converters and inverters
- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS compliant

## Applications

The following are the applications of the MSCSM120TAM16TPAG device:

- Uninterruptible power supplies
- Welding converters
- Switched mode power supplies
- EV motor and traction drive

## 1. Electrical Specifications

This section provides the electrical specifications of the MSCSM120TAM16TPAG device.

### 1.1 SiC MOSFET Characteristics (Per SiC MOSFET)

The following table lists the absolute maximum ratings of the MSCSM120TAM16TPAG device.

**Table 1-1. Absolute Maximum Ratings**

Symbol	Parameter	Maximum Ratings	Unit
$V_{DSS}$	Drain-Source voltage	1200	V
$I_D$	Continuous drain current	$T_C = 25\text{ }^\circ\text{C}$	171 <sup>1</sup>
		$T_C = 80\text{ }^\circ\text{C}$	136 <sup>1</sup>
$I_{DM}$	Pulsed drain current	350	
$V_{GS}$	Gate-Source voltage	-10/23	V
$R_{DS(on)}$	Drain-Source ON resistance	16	m $\Omega$
$P_D$	Power dissipation	$T_C = 25\text{ }^\circ\text{C}$	728

**Note:**

1. Specification of SiC MOSFET device but output current must be limited due to the size of power connectors.

The following table lists the electrical characteristics of the MSCSM120TAM16TPAG device.

**Table 1-2. Electrical Characteristics**

Symbol	Characteristics	Test Conditions	Min.	Typ.	Max.	Unit	
$I_{DSS}$	Zero gate voltage drain current	$V_{GS} = 0V$ $V_{DS} = 1200V$	—	20	200	$\mu\text{A}$	
$R_{DS(on)}$	Drain-Source on resistance	$V_{GS} = 20V$ $I_D = 80A$	$T_J = 25\text{ }^\circ\text{C}$	—	12.5	16	m $\Omega$
			$T_J = 175\text{ }^\circ\text{C}$	—	20	—	
$V_{GS(th)}$	Gate threshold voltage	$V_{GS} = V_{DS}$ $I_D = 6\text{ mA}$	1.8	2.8	—	V	
$I_{GSS}$	Gate-Source leakage current	$V_{GS} = 20V$ $V_{DS} = 0V$	—	—	200	nA	

# MSCSM120TAM16TPAG

## Electrical Specifications

The following table lists the dynamic characteristics of the MSCSM120TAM16TPAG device.

**Table 1-3. Dynamic Characteristics**

Symbol	Characteristics	Test Conditions	Min.	Typ.	Max.	Unit
$C_{iss}$	Input capacitance	$V_{GS} = 0V$	—	6040	—	pF
$C_{oss}$	Output capacitance	$V_{DS} = 1000V$ $f = 1\text{ MHz}$	—	540	—	
$C_{rss}$	Reverse transfer capacitance		—	50	—	
$Q_g$	Total gate charge	$V_{GS} = -5V/20V$	—	464	—	nC
$Q_{gs}$	Gate-source charge	$V_{Bus} = 800V$ $I_D = 80A$	—	82	—	
$Q_{gd}$	Gate-drain charge		—	100	—	
$T_{d(on)}$	Turn-on delay time	$V_{GS} = -5V/20V$	—	30	—	ns
$T_r$	Rise time	$V_{Bus} = 600V$	—	30	—	
$T_{d(off)}$	Turn-off delay time	$I_D = 100A$	—	50	—	
$T_f$	Fall time	$R_{GON} = 4\Omega$ $R_{GOFF} = 2.4\Omega$	—	25	—	
$E_{on}$	Turn-on energy	$V_{GS} = -5V/20V$	—	2.4	—	mJ
$E_{off}$	Turn-off energy	$V_{Bus} = 600V$ $I_D = 100A$ $R_{GON} = 4\Omega$ $R_{GOFF} = 2.4\Omega$				mJ
$R_{Gint}$	Internal gate resistance		—	2.94	—	$\Omega$
$R_{thJC}$	Junction-to-case thermal resistance		—	—	0.206	$^{\circ}C/W$

The following table lists the body diode ratings and characteristics of the MSCSM120TAM16TPAG device.

**Table 1-4. Body Diode Ratings and Characteristics**

Symbol	Characteristics	Test Conditions	Min.	Typ.	Max.	Unit
$V_{SD}$	Diode forward voltage	$V_{GS} = 0V$ $I_{SD} = 80A$	—	4	—	V
		$V_{GS} = -5V$ $I_{SD} = 80A$	—	4.2	—	
$t_{rr}$	Reverse recovery time	$I_{SD} = 80A$	—	90	—	ns
$Q_{rr}$	Reverse recovery charge	$V_{GS} = -5V$	—	1100	—	nC
$I_{rr}$	Reverse recovery current	$V_R = 800V$ $di_f/dt = 2000\text{ A}/\mu s$	—	27	—	A

### 1.2 Thermal and Package Characteristics

The following table lists the package characteristics of the MSCSM120TAM16TPAG device.

**Table 1-5. Thermal and Package Characteristics**

Symbol	Characteristic	Min.	Max.	Unit		
V <sub>ISOL</sub>	RMS isolation voltage, any terminal to case t = 1 min, 50 Hz/60 Hz	4000	—	V		
T <sub>J</sub>	Operating junction temperature range	−40	175	°C		
T <sub>JOP</sub>	Recommended junction temperature under switching conditions	−40	T <sub>Jmax</sub> −25			
T <sub>STG</sub>	Storage temperature range	−40	125			
T <sub>C</sub>	Operating case temperature	−40	125			
Torque	Mounting torque	To heatsink	M6	3	5	N.m
Wt	Package weight	—	250			g

The following table lists the temperature sensor NTC of the MSCSM120TAM16TPAG device.

**Table 1-6. Temperature Sensor NTC**

Symbol	Characteristic	Min.	Typ.	Max.	Unit
R <sub>25</sub>	Resistance at 25°C	—	50	—	kΩ
ΔR <sub>25</sub> /R <sub>25</sub>	—	—	5	—	%
B <sub>25/85</sub>	T <sub>25</sub> = 298.15 K	—	3952	—	K
ΔB/B	—	T <sub>C</sub> = 100 °C	4	—	%

$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T} - \frac{1}{T_{25}}\right)\right]}$$

T: Thermistor temperature  
R<sub>T</sub>: Thermistor value at T

**Note:** See [APT0406—Using NTC Temperature Sensor Integrated into Power Module](#) for more information.

### 1.3 Typical SiC MOSFET Performance Curve

The following figures show the SiC MOSFET performance curves of the MSCSM120TAM16TPAG device.

Figure 1-1. Maximum Thermal Impedance

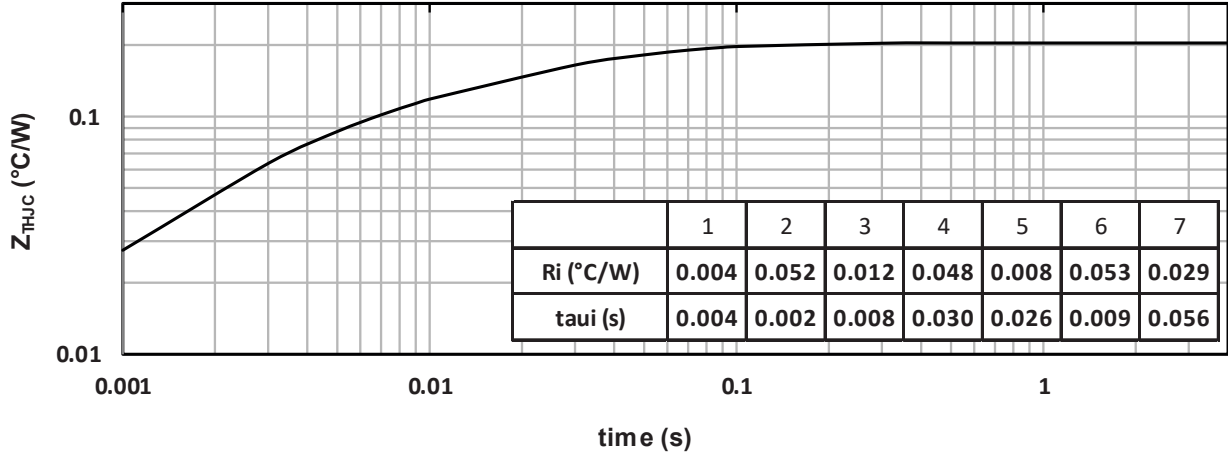


Figure 1-2. Output Characteristics,  $T_J = 25^\circ\text{C}$

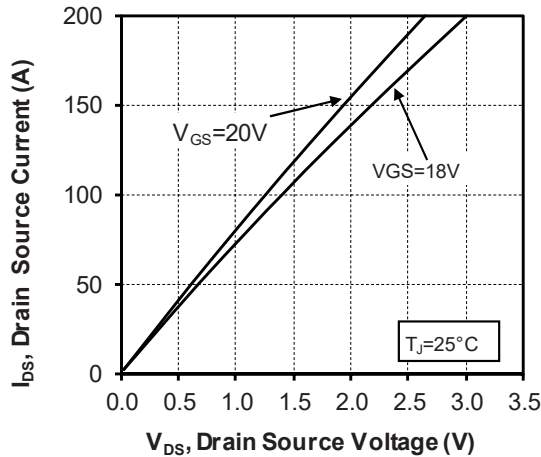


Figure 1-3. Output Characteristics,  $T_J = 175^\circ\text{C}$

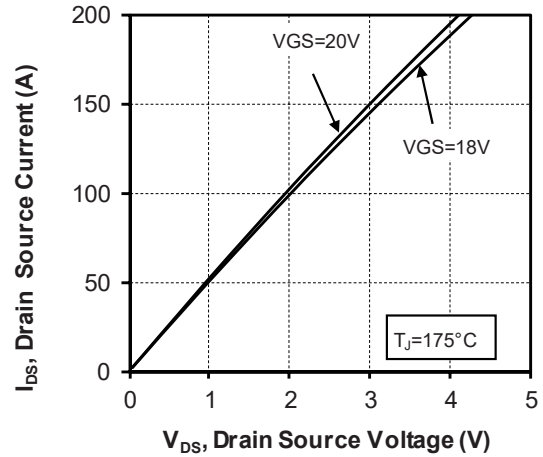


Figure 1-4. Normalized  $R_{DS(on)}$  vs. Temperature

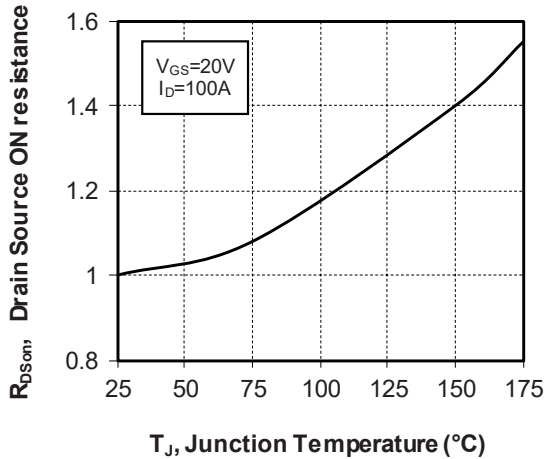
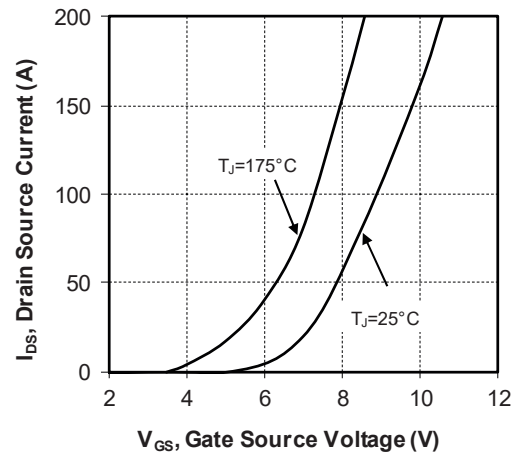


Figure 1-5. Transfer Characteristics



# MSCSM120TAM16TPAG

## Electrical Specifications

Figure 1-6. Switching Energy vs. Rg

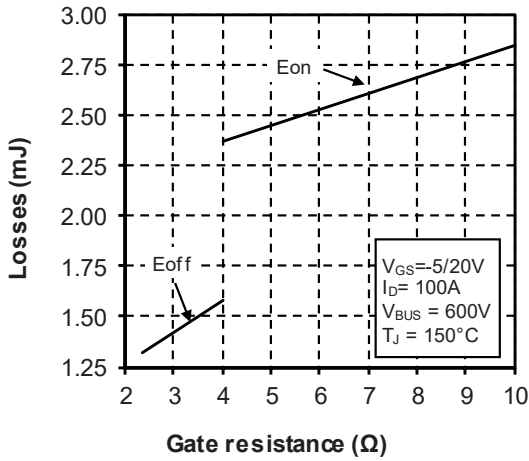


Figure 1-7. Switching Energy vs. Current

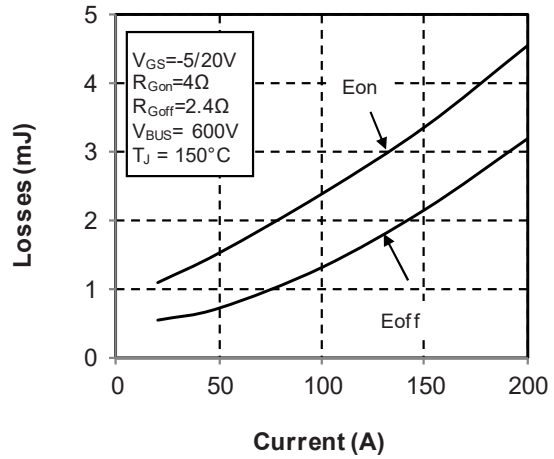


Figure 1-8. Capacitance vs. Drain Source Voltage

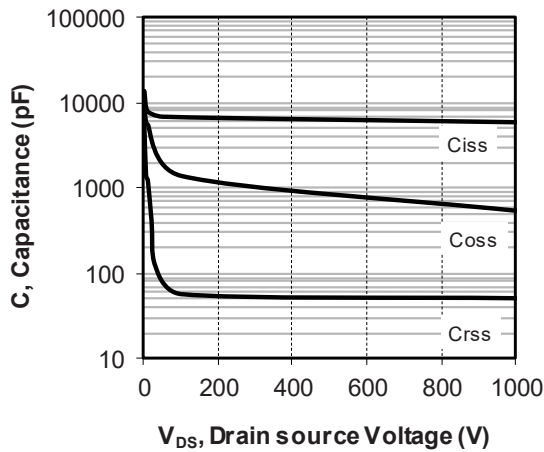


Figure 1-9. Gate Charge vs. Gate Source Voltage

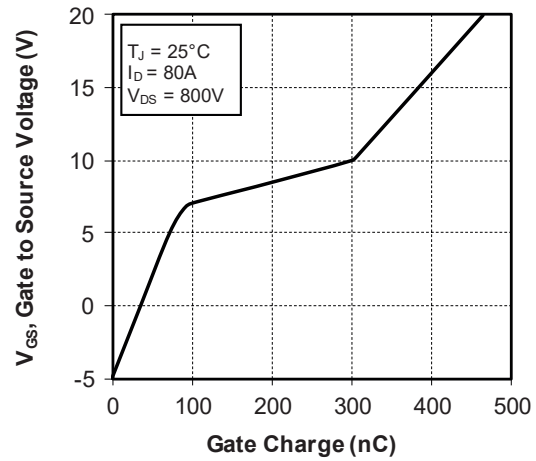


Figure 1-10. Body Diode Characteristics,  $T_J = 25^\circ C$

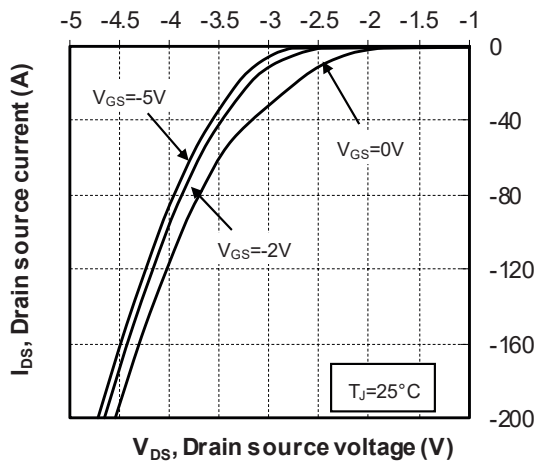


Figure 1-11. 3<sup>rd</sup> Quadrant Characteristics,  $T_J = 25^\circ C$

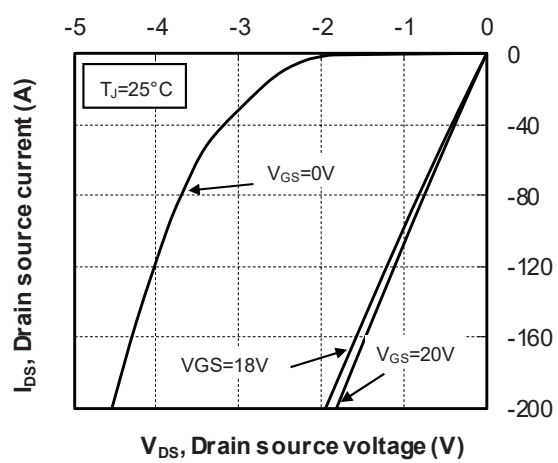


Figure 1-12. Body Diode Characteristics,  $T_J = 175^\circ\text{C}$

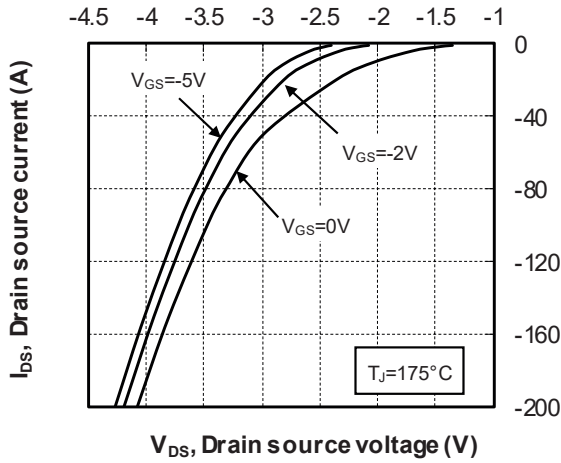


Figure 1-13. 3<sup>rd</sup> Quadrant Characteristics,  $T_J = 175^\circ\text{C}$

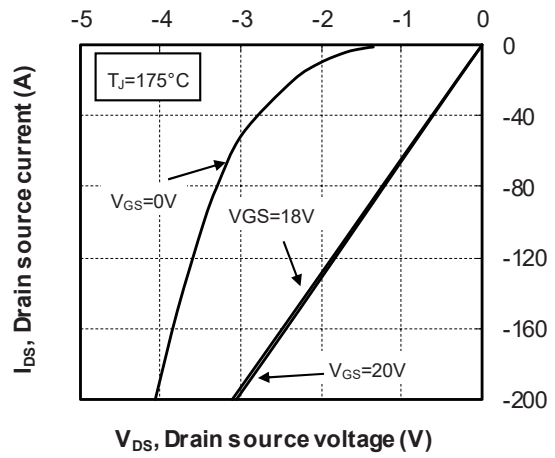
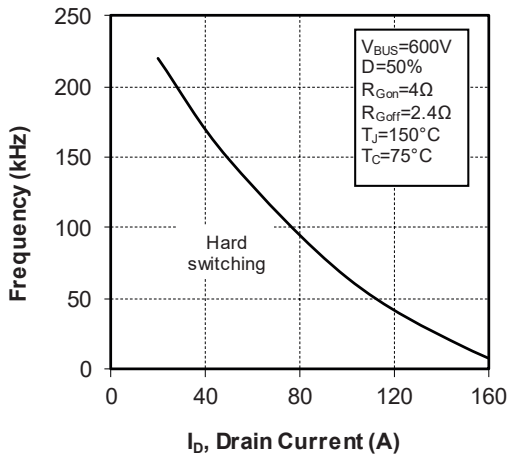


Figure 1-14. Operating Frequency vs. Drain Current





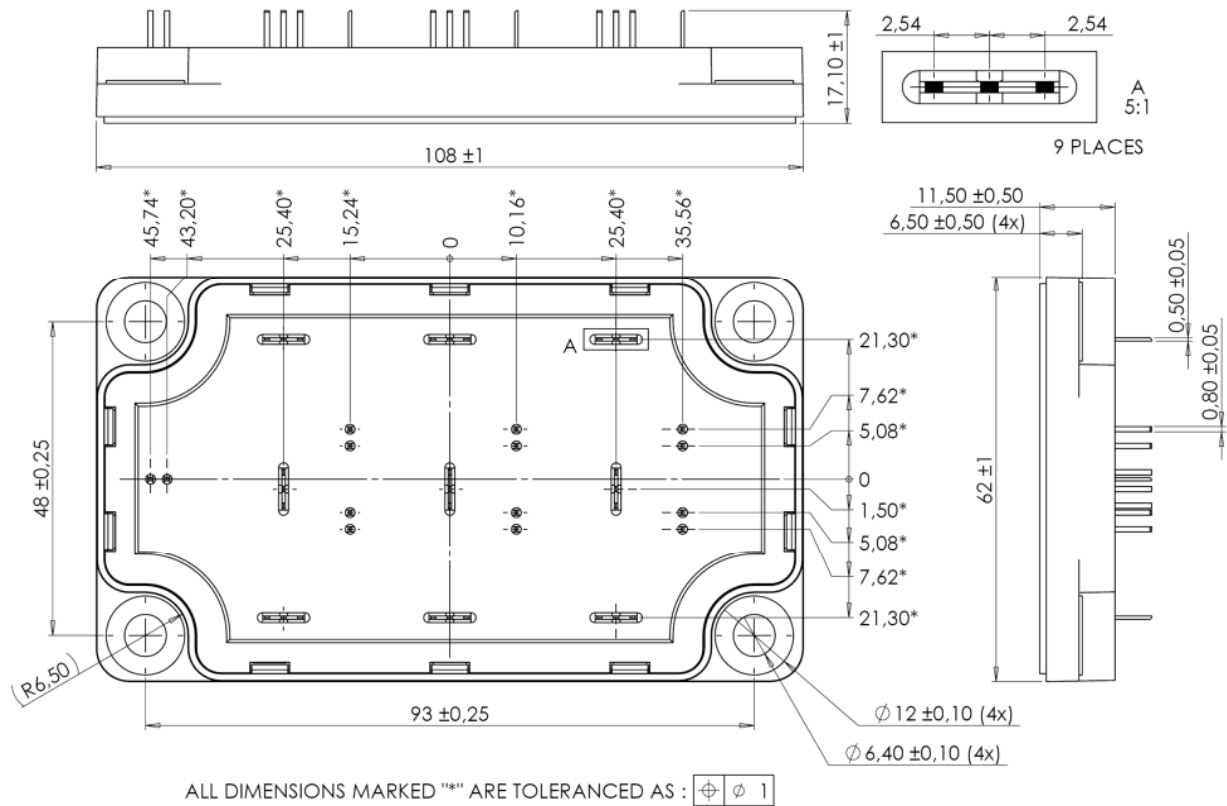
## 2. Package Specifications

The following section shows the package specification of the MSCSM120TAM16TPAG device.

### 2.1 Package Outline

The following figure shows the package outline drawing of the MSCSM120TAM16TPAG device. The dimensions in the following figure are in millimeters.

Figure 2-1. Package Outline Drawing



**Note:** See [AN1902—Mounting Instructions for SP6-P \(12 mm\) Power Modules](#) for more Information.

### 3. Revision History

Revision	Date	Description
A	06/2022	Initial Revision

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